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April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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HAT1126R, HAT1126RJ

Silicon P Channel Power MOS FET
High Speed Power Switching

REJ03G0406-0100

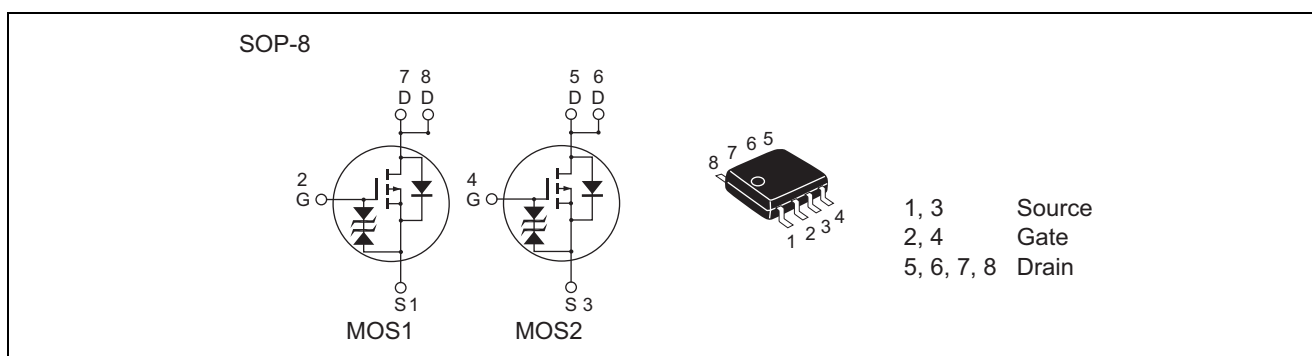
Rev.1.00

Sep.10.2004

Features

- Low on-resistance
- Capable of 4.5 V gate drive
- High density mounting
- “J” is for Automotive application
High temperature D-S leakage guarantee
Avalanche rating

Outline



Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings		Unit
		HAT1126R	HAT1126RJ	
Drain to source voltage	V_{DSS}	-60	-60	V
Gate to source voltage	V_{GSS}	±20	±20	V
Drain current	I_D	-6.0	-6.0	A
Drain peak current	I_D (pulse) ^{Note1}	-48	-48	A
Avalanche current	I_{AP} ^{Note4}	—	-6.0	A
Avalanche energy	E_{AR} ^{Note4}	—	3.08	mJ
Channel dissipation	P_{ch} ^{Note2}	2	2	W
Channel dissipation	P_{ch} ^{Note3}	3	3	W
Channel temperature	T_{ch}	150	150	°C
Storage temperature	T_{stg}	-55 to +150	-55 to +150	°C

Notes: 1. $PW \leq 10\mu s$, duty cycle $\leq 1\%$

2. 1 Drive operation: When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), $PW \leq 10$ s

3. 2 Drive operation: When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), $PW \leq 10$ s

4. Value at $T_{ch} = 25^\circ C$, $R_g \geq 50 \Omega$

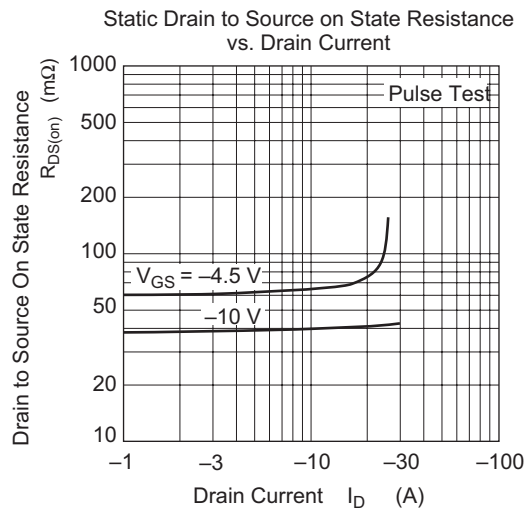
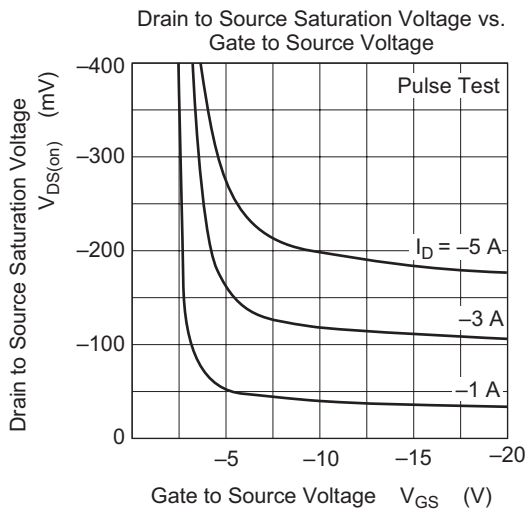
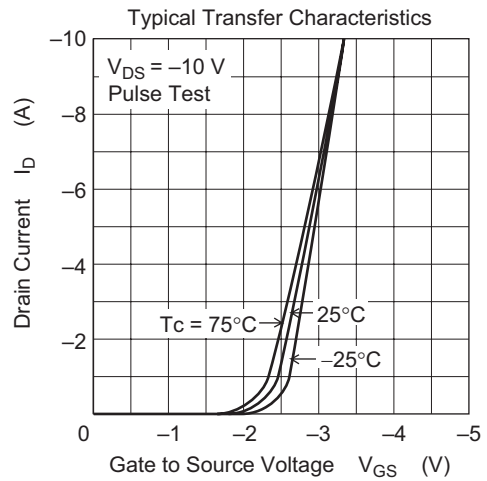
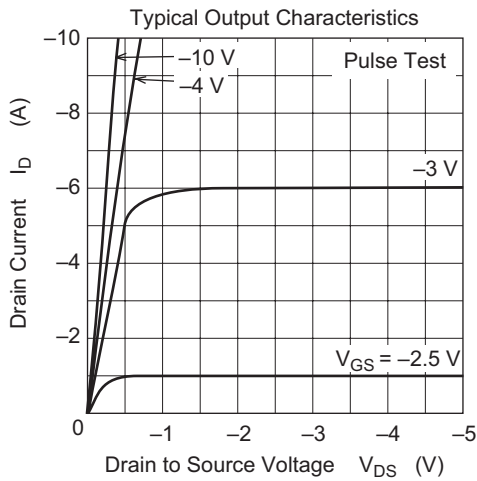
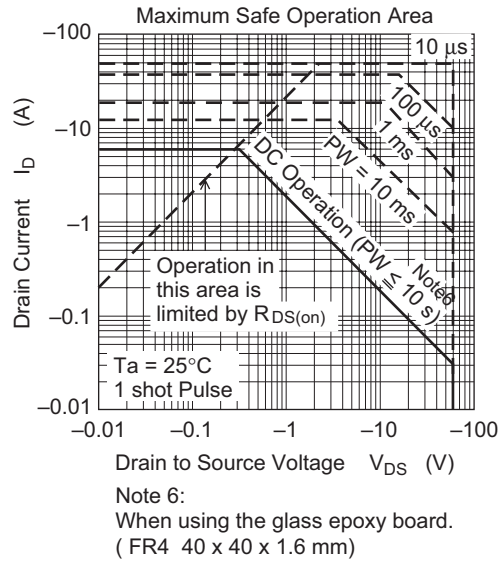
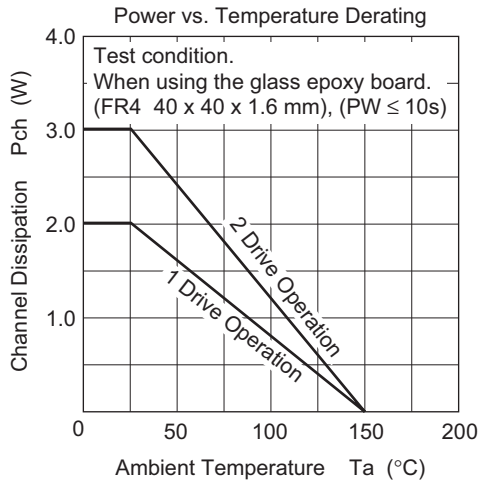
Electrical Characteristics

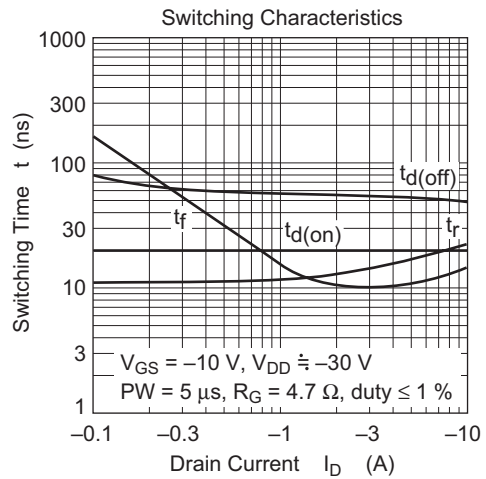
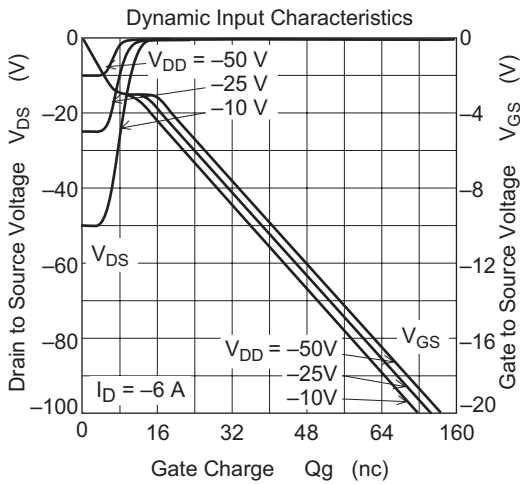
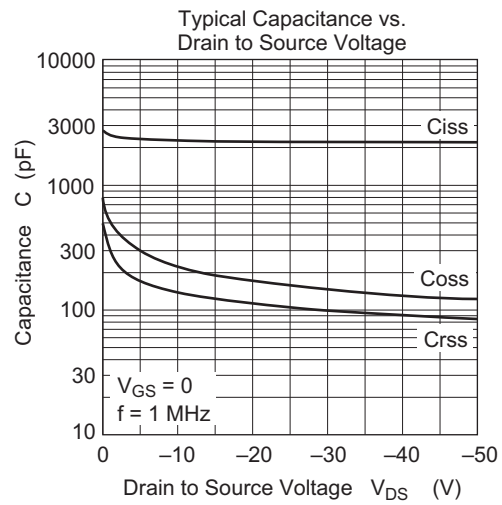
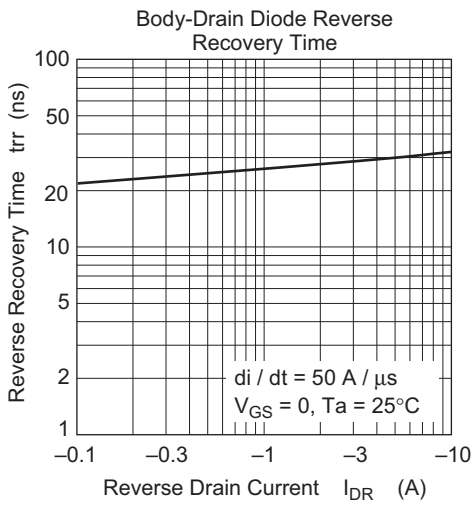
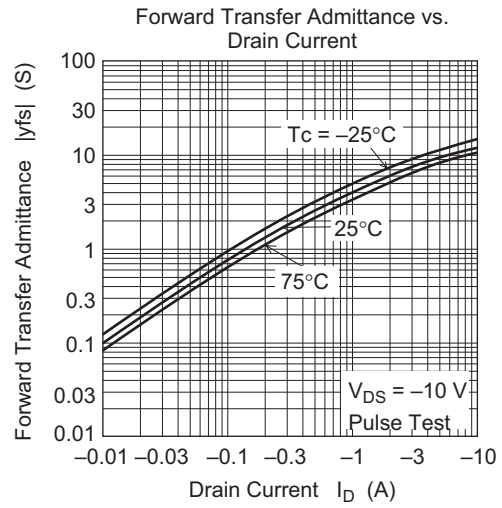
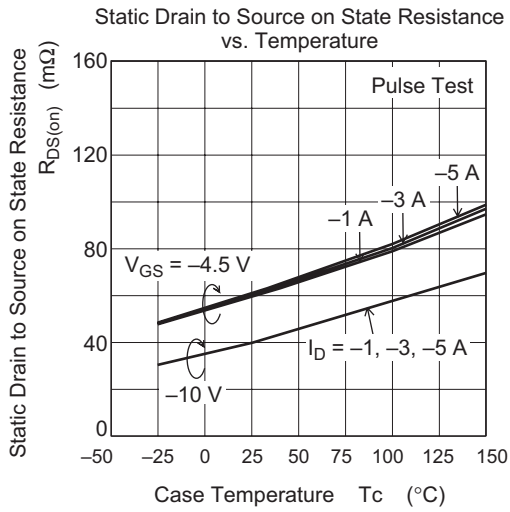
(Ta = 25°C)

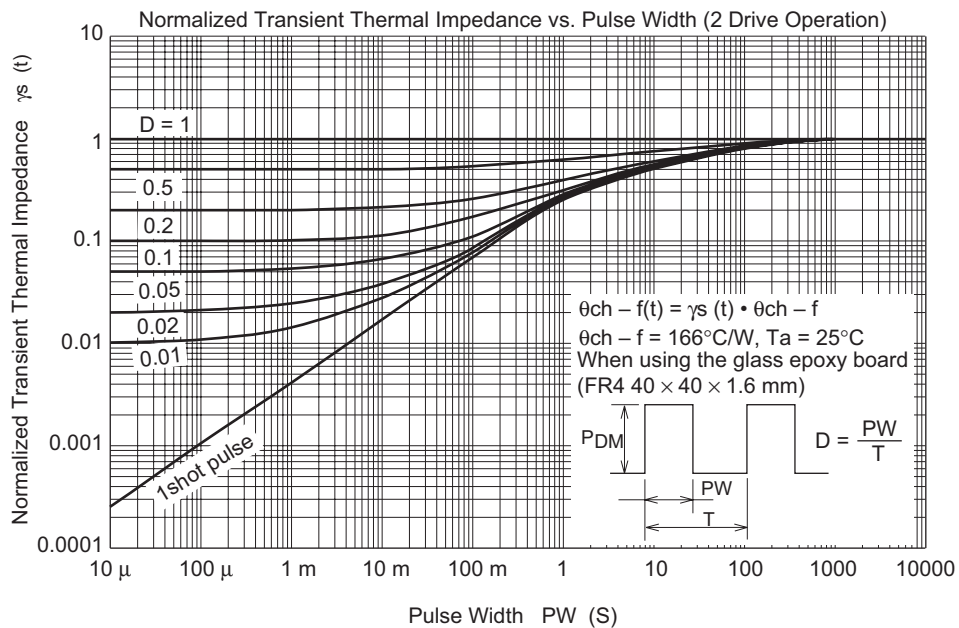
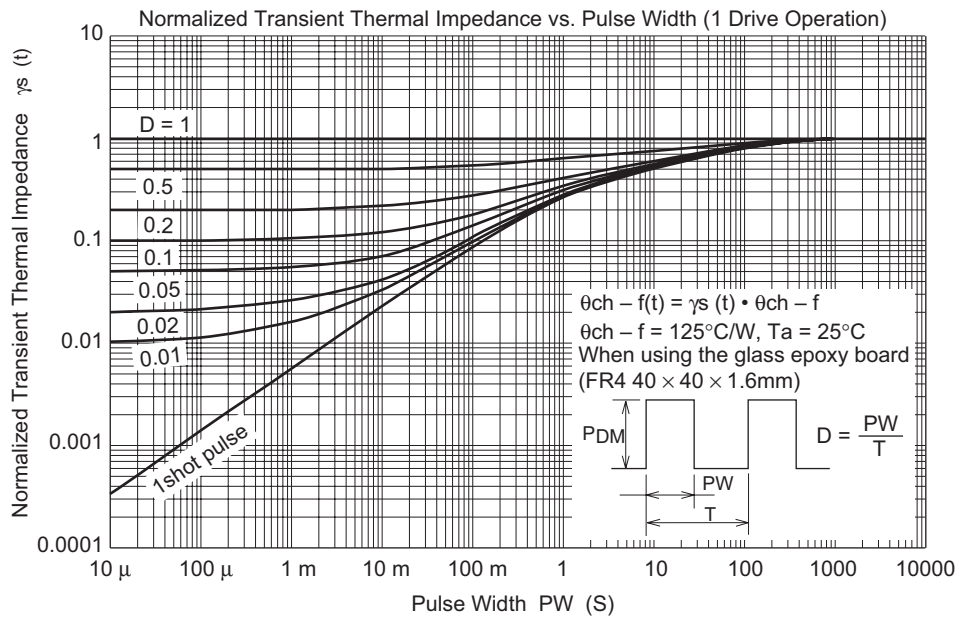
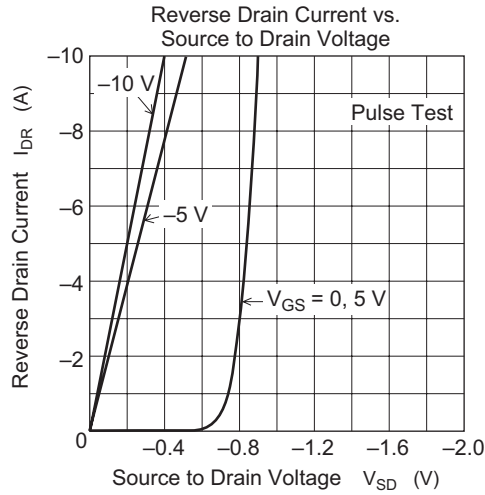
Item	Symbol	Min	Typ	Max	Unit	Unit
Drain to source breakdown voltage	$V_{(BR)DSS}$	-60	—	—	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to Source breakdown voltage	$V_{(BR)GSS}$	± 20	—	—	V	$I_G = \pm 100 \text{ }\mu\text{A}, V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	-1	μA	$V_{DS} = -60 \text{ V}, V_{GS} = 0$
Zero gate voltage drain current	HAT1126R	I_{DSS}	—	—	μA	$V_{DS} = -48 \text{ V}, V_{GS} = 0$
	HAT1126RJ	I_{DSS}	—	—	-10	μA
Gate to source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	—	-2.5	V	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$
Forward transfer admittance	$ y_{fs} $	4.0	7.0	—	S	$I_D = -3.0 \text{ A}^{\text{Note5}}, V_{DS} = -10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	40	50	m Ω	$I_D = -3.0 \text{ A}^{\text{Note5}}, V_{GS} = -10 \text{ V}$
	$R_{DS(on)}$	—	60	85	m Ω	$I_D = -3.0 \text{ A}^{\text{Note5}}, V_{GS} = -4.5 \text{ V}$
Input capacitance	C_{iss}	—	2300	—	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0$
Output capacitance	C_{oss}	—	230	—	pF	$f = 1 \text{ MHz}$
Reverse transfer capacitance	C_{rss}	—	140	—	pF	
Total gate charge	Q_g	—	37	—	nC	$V_{DD} = -25 \text{ V}$
Gate to source charge	Q_{gs}	—	6.5	—	nC	$V_{GS} = -10 \text{ V}$
Gate to drain charge	Q_{gd}	—	8	—	nC	$I_D = -6.0 \text{ A}$
Turn-on delay time	$t_{d(on)}$	—	20	—	ns	$V_{GS} = -10 \text{ V}, I_D = -3.0 \text{ A}$
Rise time	t_r	—	15	—	ns	$V_{DD} \cong -30 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	55	—	ns	$R_L = 10 \text{ }\Omega$
Fall time	t_f	—	10	—	ns	$R_G = 4.7 \text{ }\Omega$
Body-drain diode forward voltage	V_{DF}	—	-0.85	-1.1	V	$I_F = -6.0 \text{ A}, V_{GS} = 0^{\text{Note5}}$
Body-drain diode reverse recovery time	t_{rr}	—	30	—	ns	$I_F = -6.0 \text{ A}, V_{GS} = 0$ $diF/dt = 100 \text{ A} / \mu\text{s}$

Notes: 5. Pulse test

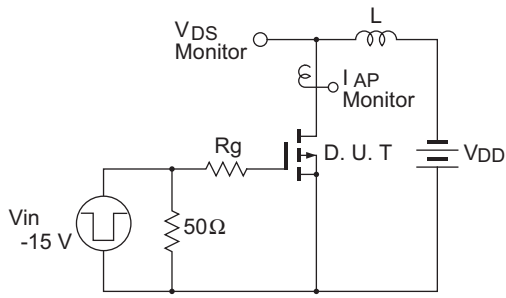
Main Characteristics



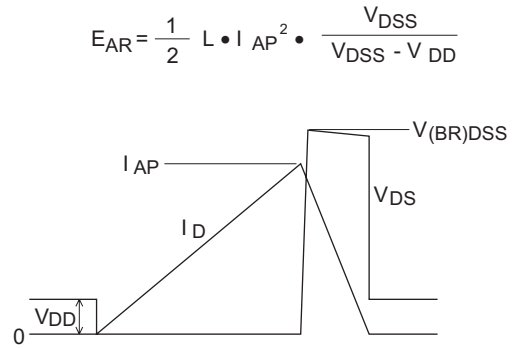




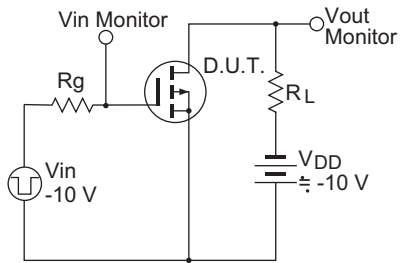
Avalanche Test Circuit



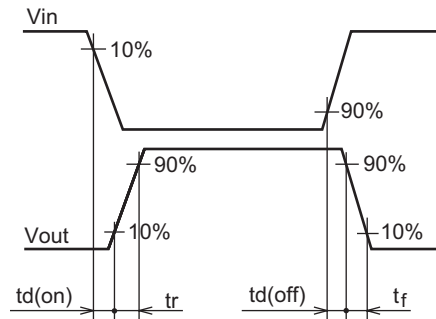
Avalanche Waveform



Switching Time Test Circuit

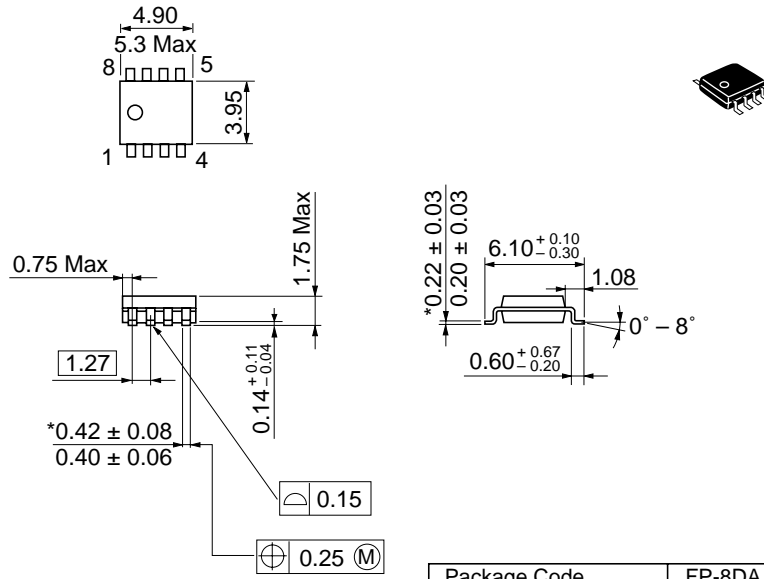


Switching Time Waveform



Package Dimensions

As of January, 2003
Unit: mm



*Dimension including the plating thickness
Base material dimension

Package Code	FP-8DA
JEDEC	Conforms
JEITA	—
Mass (reference value)	0.085 g

Ordering Information

Part Name	Quantity	Shipping Container
HAT1126R-EL-E	2500 pcs	Taping
HAT1126RJ-EL-E	2500 pcs	Taping

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